

Two-line TVS Diode

## **General Description**

The AOZ8222DI-05 is a two-line transient voltage suppressor diode designed to protect voltage sensitive electronics from high transient conditions and ESD.

This device incorporates two TVS diodes in an ultra-small DFN 1.0 x 0.6 package. During transient conditions, the TVS diodes directs the transient to ground. The AOZ8222DI-05 may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 ( $\pm$  15 kV air,  $\pm$  8 kV contact discharge).

The AOZ8222DI-05 comes in an RoHS compliant 3-lead DFN package and is rated over a -40  $^{\circ}$  to +85  $^{\circ}$  ambient temperature range.

The ultra-small 1.0 mm x 0.6 mm x 0.5 mm DFN package makes it ideal for applications where PCB space is a premium. The small size and high ESD protection makes it ideal for protecting voltage sensitive electronics from high transient conditions and ESD.

#### **Features**

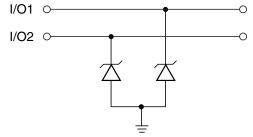
- ESD protection for high-speed data lines:
  - Exceeds IEC 61000-4-2 (ESD): ± 20 kV (air),
    ± 20 kV (contact)
  - Human Body Model (HBM) ± 30 kV
- Small package saves board space
- Low insertion loss
- Low clamping voltage
- Low operating voltage: 5 V

## **Applications**

- Portable handheld devices
- Keypads, data lines, buttons
- Notebook computers
- Digital Cameras
- Portable GPS
- MP3 players

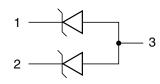


# Typical Application



Unidirection Protection of Two Line

# **Pin Configuration**





## **Ordering Information**

Part Number	Ambient Temperature Range	Package	Environmental
AOZ8222DI-05	-40 ℃ to +85 ℃	DFN 1.0 x 0.6-3L	Green Product



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant.

Please visit www.aosmd.com/media/AOSGreenPolicy.pdf for additional information.

### **Absolute Maximum Ratings**

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	AOZ8222DI-05DI-05			
Peak Pulse Current, t <sub>P</sub> = 8/20 μs	5.5 A			
Peak Pulse Power, t <sub>P</sub> = 8/20 μs	50 W			
Storage Temperature (T <sub>S</sub> )	-65 ℃ to +150 ℃			
ESD Rating per IEC61000-4-2, Contact <sup>(1)</sup>	± 20 kV			
ESD Rating per IEC61000-4-2, Air <sup>(1)</sup>	± 20 kV			
ESD Rating per Human Body Model <sup>(2)</sup>	± 30 kV			

#### Notes:

- 1. IEC 61000-4-2 discharge with  $C_{Discharge}$  = 150 pF,  $R_{Discharge}$  = 330  $\Omega$ . 2. Human Body Discharge per MIL-STD-883, Method 3015  $C_{Discharge}$  = 100 pF,  $R_{Discharge}$  = 1.5 k $\Omega$ .

# **Maximum Operating Ratings**

Parameter	Rating
Junction Temperature (T <sub>J</sub> )	-40 ℃ to +125 ℃

Rev. 2.0 August 2013 www.aosmd.com Page 2 of 7



## **Electrical Characteristics**

 $T_A = 25 \text{ }^{\circ}\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V <sub>RWM</sub>	Reverse Working Voltage Between I/O and VN <sup>(3)</sup>				5.0	V
V <sub>BR</sub>	Reverse Breakdown Voltage	I <sub>T</sub> = 1 mA, between I/O and VN <sup>(4)</sup>	6.0			V
I <sub>R</sub>	Reverse Leakage Current	V <sub>RWM</sub> = 5 V, between I/O and VN			1	μΑ
V <sub>F</sub>	Diode Forward Voltage	I <sub>F</sub> = 10 mA	0.6	0.7	0.9	V
V <sub>CL</sub>	Channel Clamp Voltage Positive Transients Negative Transients	$I_{PP} = 1 \text{ A}$ , $tp = 100 \text{ ns}$ , any I/O pin to Ground <sup>(5)(6)</sup>			8.0 -2.0	V V
	Channel Clamp Voltage Positive Transients Negative Transients	$I_{PP} = 5 \text{ A}$ , $tp = 100 \text{ ns}$ , any I/O pin to Ground <sup>(5)(6)</sup>			9.0 -5.0	V V
	Channel Clamp Voltage Positive Transients Negative Transients	$I_{PP} = 12 \text{ A}$ , $tp = 100 \text{ ns}$ , any I/O pin to $Ground^{(5)(6)}$			10.0 -10.0	V V
СЈ	Channel Input Capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, between I/O pins <sup>(6)</sup>		8	9	pF
		$V_R = 0 \text{ V}, f = 1 \text{ MHz}, \text{ any I/O pin to Ground}^{(6)}$		15	18	pF

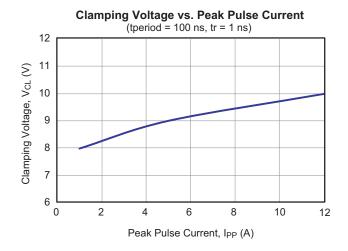
## Notes:

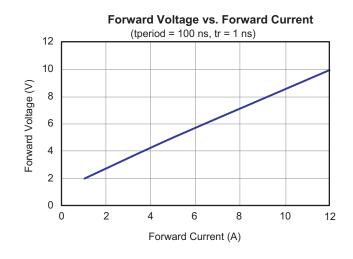
- 3. The working peak reverse voltage, VRWM, should be equal to or greater than the DC or continuous peak operating voltage level.
- 4.  $V_{BR}$  is measured at the pulse test current  $I_{T}$ .
- 5. Measurements performed using a 100ns Transmission Line Pulse (TLP) system.
- 6. Guaranteed by design and characterization.

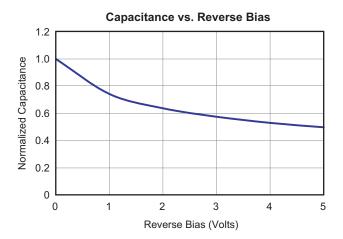
Rev. 2.0 August 2013 www.aosmd.com Page 3 of 7

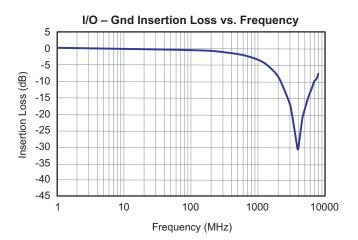


# **Typical Performance Characteristics**





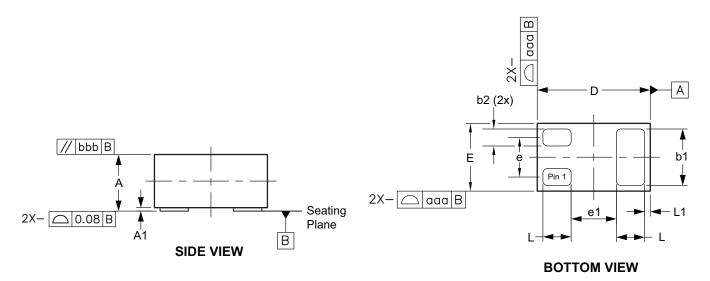




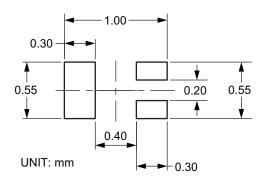
Rev. 2.0 August 2013 www.aosmd.com Page 4 of 7



# Package Dimensions, DFN 1.0 x 0.6, 3L



### **RECOMMENDED LAND PATTERN**



### **Dimensions in millimeters**

Symbols	Min.	Nom.	Max.		
Α	0.50	0.52	0.55		
A1	0.00	0.03	0.05		
b1	0.45	0.50	0.55		
b2	0.10	0.15	0.20		
D	0.95	1.00	1.075		
Е	0.55	0.60	0.675		
е	_	0.35	_		
e1	_	0.40	_		
L	0.20	0.25	0.30		
L1	_	0.05	_		
aaa		0.15			
bbb		0.05			

## **Dimensions in inches**

Symbols	Min.	Nom.	Max.			
Α	0.019	0.020	0.022			
A1	0.000	0.001	0.002			
b1	0.018	0.020	0.022			
b2	0.004	0.006	0.008			
D	0.037	0.039	0.042			
Е	0.022	0.024	0.027			
е	_	0.014	_			
e1	_	0.016	_			
L	0.008	0.010	0.012			
L1	_	0.002	_			
aaa	0.006					
bbb		0.002				

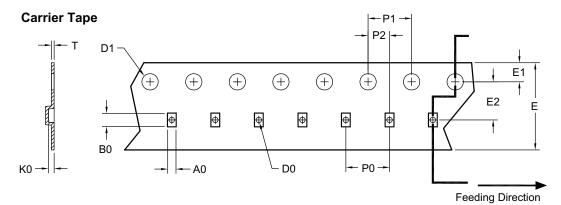
#### Notes:

- 1. All dimensions are in millimeters, angles are in degrees.
- 2. Coplanarity applies to the exposed heat sink slug as well as the terminals.

Rev. 2.0 August 2013 www.aosmd.com Page 5 of 7



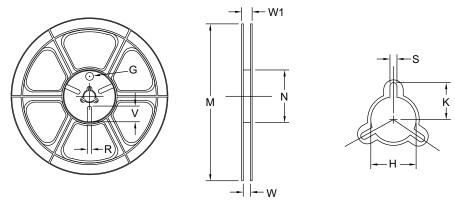
# Tape and Reel Dimensions, DFN 1.0 x 0.6, 3L



UNIT: mm

Package	A0	В0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
DFN 1.0x0.6	0.76	1.21	0.53	ø0.50	ø1.50	8.00	1.75	3.50	4.00	4.0	2.0	0.254
(8 mm)	±0.05	±0.05	±0.05	±0.05	±0.10	+0.30/-0.10	±0.1	±0.05	±0.10	±0.10	±0.05	±0.02

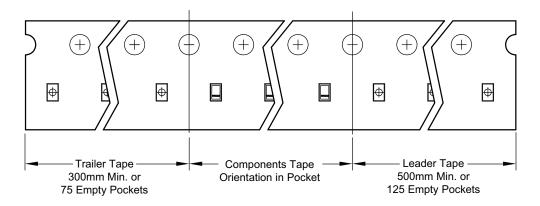




UNIT: mm

Tape Size	Reel Size	М	N	W	W1	Н	K	S	G	R	٧
8mm	ø178	ø178 ±0.5	ø55 ±1	8.4 +1.5/-0	14.4. Max.	ø13.0 ±0.5	2.0 ±0.5	2.0 ±0.5	N/A	N/A	N/A

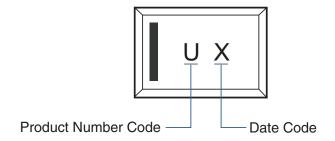
### Leader / Trailer & Orientation



Rev. 2.0 August 2013 www.aosmd.com Page 6 of 7



## **Part Marking**



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Rev. 2.0 August 2013 www.aosmd.com Page 7 of 7